

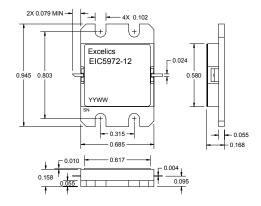
UPDATED 02/17/2006

# 5.90-7.20 GHz 12-Watt Internally Matched Power FET

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### **FEATURES**

- 5.90-7.20GHz Bandwidth
- Input/Output Impedance Matched to 50 Ohms
- +41.5 dBm Output Power at 1dB Compression
- 8.0 dB Power Gain at 1dB Compression
- 36% Power Added Efficiency
- -46 dBc IM3 at PO = 30.5 dBm SCL
- Hermetic Metal Flange Package
- 100% Tested for DC, RF, and R<sub>TH</sub>



# ELECTRICAL CHARACTERISTICS ( $T_a = 25^{\circ}C$ )

#### Caution! ESD sensitive device.

EIC5972-12

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SYMBOL	PARAMETERS/TEST CONDITIONS <sup>1</sup>	MIN	ТҮР	MAX	UNITS
$P_{1dB}$	Output Power at 1dB Compression $f = 5.90-7.20$ GHz $V_{DS} = 10 \text{ V}, I_{DSQ} \approx 3200$ mA	40.5	41.5		dBm
G <sub>1dB</sub>	Gain at 1dB Compressionf = 5.90-7.20GHz $V_{DS}$ = 10 V, $I_{DSQ} \approx 3200$ mA	7.0	8.0		dB
∆G	Gain Flatnessf = $5.90-7.20$ GHz $V_{DS}$ = $10$ V, $I_{DSQ} \approx 3200$ mA			±0.8	dB
PAE	Power Added Efficiency at 1dB Compression $V_{DS}$ = 10 V, $I_{DSQ} \approx$ 3200mA f = 5.90-7.20GHz	<u>.</u>	36		%
Id <sub>1dB</sub>	Drain Current at 1dB Compression f = 5.90-7.20GHz	2	3300	3700	mA
IM3	Output 3rd Order Intermodulation Distortion $\Delta f$ = 10 MHz 2-Tone Test; Pout = 30.5 dBm S.C.L <sup>2</sup> $V_{DS}$ = 10 V, $I_{DSQ} \approx 65\%$ IDSSf = 7.20GHz	-43	-46		dBc
I <sub>DSS</sub>	Saturated Drain Current $V_{DS}$ = 3 V, $V_{GS}$ = 0 V		6200	7800	mA
V <sub>P</sub>	Pinch-off Voltage V <sub>DS</sub> = 3 V, I <sub>DS</sub> = 62 mA		-2.5	-4.0	V
R <sub>TH</sub>	Thermal Resistance <sup>3</sup>		2.5	3.0	°C/W

Note: 1) Tested with 50 Ohm gate resistor. 2) S.C.L. = Single Carrier Level. 3)

3) Overall Rth depends on case mounting

#### MAXIMUM RATING AT 25°C<sup>1,2</sup>

SYMBOLS	PARAMETERS	ABSOLUTE <sup>1</sup>	CONTINUOUS <sup>2</sup>
Vds	Drain-Source Voltage	15	10V
Vgs	Gate-Source Voltage	-5	-4V
lgsf	Forward Gate Current	129.6mA	43.2mA
lgsr	Reserve Gate Current	-21.6mA	-7.2mA
Pin	Input Power	40.5dBm	@ 3dB Compression
Tch	Channel Temperature	175 °C	175 °C
Tstg	Storage Temperature	-65 to +175 °C	-65 to +175 °C
Pt	Total Power Dissipation	50W	50W

Note: 1. Exceeding any of the above ratings may result in permanent damage. 2. Exceeding any of the above ratings may reduce MTTF below design goals.